## NSN 5961-00-106-7145



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-106-7145 **Inclosure Material:** Metal **Overall Length:** 0.460 inches **Overall Diameter:** 0.610 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 220.0 breakdown voltage, collector-to-base, emitter open and 8.0 breakdown voltage, emitter-to-base, collector open and 200.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** 

Unf

**Terminal Type And Quantity:** 

3 tab, solder lug

**Specification Data:** 

80131-release5637 professional/industrial association specification

Shelf Life:

N/a

**Unit Of Measure:** 

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